NSN 5962-01-046-4794

Memory Microcircuit - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5962-01-046-4794
Body Length:
Between 0.750 inches and 0.770 inches
Body Width:
Between 0.260 inches and 0.280 inches
Body Height:
Between 0.140 inches and 0.160 inches
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and positive outputs and programmable and programmed and bipolar and w/decoded output and
expandable and wire-or outputs and 3-state output and w/buffered output and high speed and w/disable and w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Test Data Document:
97384-56602-40003 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Fiig:

A458a0

Demilitarization: Yes - demil/mli